EAST SEARCH

4/20/03

#	Hits	Search String	Databases
7	1154	("memory circuit" or "semiconductor memory") with (speed or frequency) with voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB
12	3217	("memory circuit" or "semiconductor memory") with (download\$2 or transfer\$3) with (data or music)	SPAT: 11S-PGPI IB: EPO: IPO: DERWENT: IBM TDR
13	51	1 and 2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB
		(download\$2 or transfer\$3) with (data or music) with ((high\$2 or level or supply)	
L4	1767	near2 voltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
L5	220	2 and 4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
97	624	(download\$2 or transfer\$3) with (data or music) with ((high\$2) near2 voltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
۲۷	72	2 and 6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
		(download\$2 or transfer\$3) with (data or music) with ((high\$2) near2 (frequency	
L8	16512	or speed))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
67	521	2 and 8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
L10	16	6 and 9	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
		((download\$2 or transfer\$3) near2 (data or music)) with ((high\$2 or level or	
L11	686	supply) near2 voltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
L12	123	2 and 11	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
	G		
L13	296	voltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
		((download\$2 or transfer\$3) near2 (data or music)) with ((high\$2) near2	
L15	13183	(frequency or speed))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
L16	445	2 and 15	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
L17	11	13 and 16	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
L14	35	2 and 13	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
		((download\$2 or transfer\$3) near2 (data or music)) with ((high\$2) near2	
L18	29	(frequency or speed)) same ((high\$2) near2 voltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
,		("memory circuit" or "semiconductor memory") same (((download\$2 or transfer\$3) near2 (data or music)) with (high\$2 near2 voltage)) same (high\$2 near2	
L19	0	(frequency or speed))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
		١.	
L20	9	near2 (data or music)) with (high\$2 near2 voltage))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
L23	10	21 and 22	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

124	13	("memory circuit" or "semiconductor memory") same (((download\$2 or transfer\$3) near2 (data or music)) with (high\$2 near2 (frequency or speed))) same voltage	USPAT: US-PGPUB: EPO: JPO: DERWENT: IBM TDB
121	285	("memory circuit" or "semiconductor memory") same (((download\$2 or transfer\$3) near2 (data or music)) with (high\$2 near2 (frequency or speed)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB
122	83	("memory circuit" or "semiconductor memory") same (((download\$2 or transfer\$3) near2 (data or music)) with ((high\$2 or level or supply) near2 voltage))	JSPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
		("memory circuit" or "semiconductor memory") same ((download\$2 or transfer\$3)	
		near2 (data or music)) same (high\$2 near2 voltage) same (high\$2 near2	
L25	4	(frequency or speed))	JSPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB
		("memory circuit" or "semiconductor memory") same (((download\$2 or transfer\$3)	
L26	10	near2 (data or music)) with (high\$2 near2 voltage))	JSPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
		("memory circuit" or "semiconductor memory") same (((download\$2 or transfer\$3)	
L27	37	near2 (data or music)) same (high\$2 near2 voltage))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
L28	141	(("digital signal" or data) near2 source) with (high\$2 near2 voltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
L29	27	(("digital signal" or data) adj source) with (high\$2 near2 voltage)	JSPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
L30	0	(("digital signal" or data) adj source) same (high\$2 near2 "operating voltage")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

2,

USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	_	_		_	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
Datters with (external near2 "power supply")	batter\$3 with ("power supply") with (higher near2 voltage)	batter\$3 with (external near2 "power supply") with (higher near2 voltage)	4,665,354.pn. and (higher with voltage)	batter\$3 with (charg\$3 or recharg\$3) with (higher near2 voltage)	3 and 5	3,660,714.pn. and (higher with voltage)	4,085,358.pn. and (battery with charge)
6/07	511		7		138	•	7
	ខា	7	L 4	L5	9 7	77	8

09/886368

Hamamoto

EAST SEARCH

6/3/03

Results of search set L18:((download\$2 or transfer\$3) near2 (data or music)) with ((high\$2) near2 (frequency or speed)) same ((high\$2) near2 voltage) US 20030190110 A1 Method and apparatus for providing inductive coupling and decoupling of high-frequency, high-bandwidth d 20031009 385/15 US 20030164723 A1 Output buffer circuit
US 20020154564 A1 Semiconductor integrated circuit device Issue Date Current OR Document Jocument II Title

Page 2 of 4

US 20020145413 A1	DC-DC converter and storage apparatus	
20020110310	Apparatus and metroo for providing a power line confinding to be less for sale transmission of right-frequency, high-bandwidth of Method and apparatus for providing inductive coupling and decoupling of high-frequency, high-bandwidth of	20020815 385/15
US 20020024069 A1	Charge transfer device	20020228 257/239
US 20020015349 A1	Semiconductor integrated circuit device	20020207 365/227
US 20010037431 A1	Digital information system, digital audio signal processor and signal converter	20011101 711/115
US 20010035785 A1	Voltage supply discriminator and method	20011101 327/333
US 6690615 B2	Semiconductor integrated circuit device	20040210 365/230.09
US 6553450 B1	Buffer to multiply memory interface	20030422 711/105
6535448	Semiconductor integrated circuit device having bidirectional data transfer between a main memory unit and	20030318 365/227
US 6531792 B2	DC-DC converter and storage apparatus	20030311 307/109
US 6515318 B2	Charge transfer device	20030204 257/239
US 6501306 B1	Data output circuit for semiconductor device with level shifter and method for outputting data using the sam	20021231 327/112
US 6480051 B2	Voltage supply discriminator and method	20021112 327/333
US 6366130 B1	High speed low power data transfer scheme	20020402 326/95
6343046	Semiconductor integrated circuit device	20020129 365/230.09
US 6307410 B1	Semiconductor integrated circuit device	20011023 327/154
US 6297683 B1	Voltage supply discriminator and method	20011002 327/333
US 6282611 B1	Digital information system, digital audio signal processor and signal converter	20010828 711/115
US 6147672 A	Display signal interface system between display controller and display apparatus	20001114 345/589
US 6130852 A	Memory integrated circuit device including a memory having a configuration suitable for mixture with logic	20001010 365/230.03
US 6101076 A	Electromagnetic safety enhancement circuit for universal serial bus systems	20000808 361/90
US 6097629 A	Non-volatile, static random access memory with high speed store capability	20000801 365/185.07
US 6097208 A	Signal-transfer system and semiconductor device for high-speed data transfer	20000801 326/26
US 6051990 A	Asymmetric current mode driver for differential transmission lines	20000418 326/33
US 6040759 A	Communication system for providing broadband data services using a high-voltage cable of a power syster	20000321 340/310.01
US 6023440 A	Semiconductor memory, moving-picture storing memory, moving-picture storing apparatus, moving-picture	20000208 365/230.03
US 5986641 A	Display signal interface system between display controller and display apparatus	19991116 345/593
US 5949733 A	Semiconductor memory, moving-picture storing memory, moving-picture storing apparatus, moving-picture	19990907 365/230.03
US 5864284 A	Apparatus for coupling radio-frequency signals to and from a cable of a power distribution network	19990126 340/310.01
US 5818761 A	Non-volatile semiconductor memory device capable of high speed programming/erasure	19981006 365/185.18
US 5805524 A	Semiconductor memory, moving-picture storing memory, moving-picture storing apparatus, moving-picture	19980908 365/238
US 5799069 A	Method and apparatus for dynamically adapting the clock rate and data transfer rate of phone-line powered	19980825 379/93.33
US 5590369 A	Bus supporting a plurality of data transfer sizes and protocols	19961231 710/110
US 555527 A	Semiconductor memory, moving-picture storing memory, moving-picture storing apparatus, moving-picture	19960910 365/222
US 5512845 A		19960430 326/88
US 5392172 A	Magnetic head circuit having a write current changeover circuit with a clamp voltage depending on write cui	19950221 360/67
5371424	Transmitter/receiver circuit and method therefor	19941206 326/63
5359298	VCO having voltage-to-current converter and PLL using same	19941025 331/2
	Sense amplifier for performing a high-speed sensing operation	
US 5302919 A	VCO having voltage-to-current converter and PLL using same	19940412 331/2